

M5L8216P / M5L8226P

T-52-09

MITSUBISHI (MICMPTR/MIPRC)

4-BIT PARALLEL BIDIRECTIONAL BUS DRIVERS

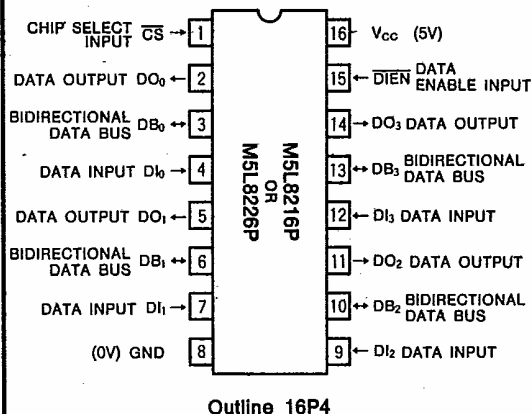
DESCRIPTION

The M5L8216P and M5L8226P are 4-bit bidirectional bus drivers and suitable for the 8-bit parallel CPU M5L8085AP.

FEATURES

- Parallel 8-bit data bus buffer driver
- Low input current $\overline{DIEN}$, $\overline{CS}$:
 $I_{IL} = -500\mu A(\text{max.})$
 DI, DB : $I_{IL} = -250\mu A(\text{max.})$
- High output current M5L8216P
 DB : $I_{OL} = 55\text{mA}(\text{max.})$
 $I_{OH} = -10\text{mA}(\text{max.})$
 DO : $I_{OH} = -1\text{mA}(\text{max.})$
M5L8226P
 DB : $I_{OL} = 50\text{mA}(\text{max.})$
 $I_{OH} = -10\text{mA}(\text{max.})$
 DO : $I_{OH} = -1\text{mA}(\text{max.})$
- Outputs can be connected with the CPU M5L8085AP: $V_{OH} = 3.65\text{V}(\text{min.})$
- Three-state output

PIN CONFIGURATION (TOP VIEW)



APPLICATION

Bidirectional bus driver/receiver for various types of micro-computer systems.

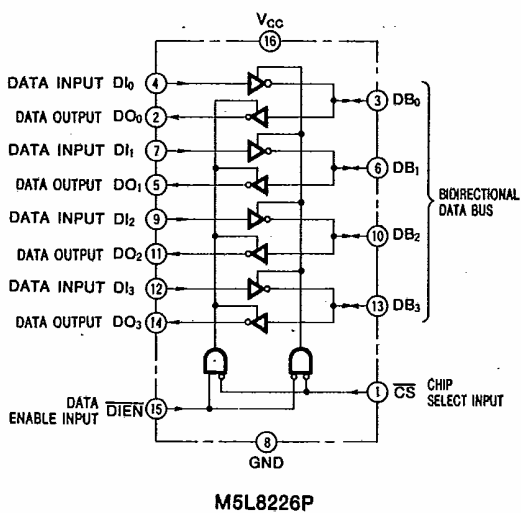
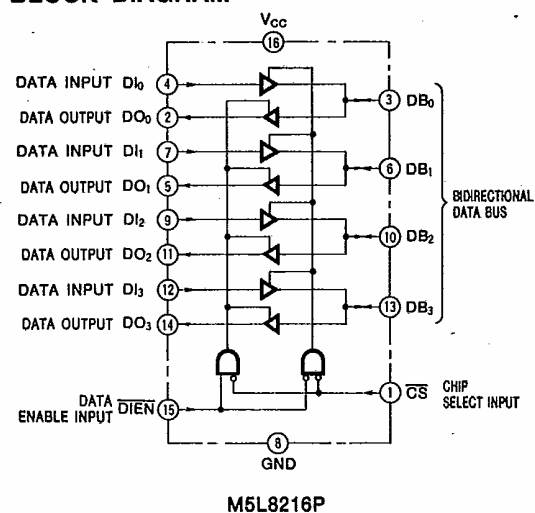
FUNCTION

The M5L8216P is a non-inverting and the M5L8226P is an inverting 4-bit bidirectional bus driver.

When the terminal $\overline{CS}$ is high-level, all outputs are in high-impedance state, and when low-level, the direction of the bidirectional bus can be controlled by the terminal $\overline{DIEN}$.

The terminal $\overline{DIEN}$ controls the data flow. The data flow control is performed by placing one of a pair of buffers in high-impedance state and allowing the other to transfer the data.

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS ($T_a=0\sim75^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Conditions	Rating	Unit
V_{CC}	Supply voltage	With respect to GND	7	V
V_I	Input voltage, CS, DIEN, DI inputs		5.5	V
V_i	Input voltage, DB Input		V_{CC}	V
V_O	High-level output voltage		V_{CC}	V
P_d	Power dissipation	$T_a=25^\circ\text{C}$	700	mW
T_{opr}	Operating free-air temperature range		$0\sim75$	$^\circ\text{C}$
T_{stg}	Storage temperature range		$-65\sim+150$	$^\circ\text{C}$

RECOMMENDED OPERATING CONDITIONS ($T_a=0\sim75^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min	Norm	Max	
V_{CC}	Supply voltage	4.75	5	5.25	V
I_{OH}	High-level output current, DO output			-1	mA
I_{OH}	High-level output current, DB output			-10	mA
I_{OL}	Low-level output current, DO output			15	mA
I_{OL}	Low-level output current, DB output			25	mA

ELECTRICAL CHARACTERISTICS ($T_a=0\sim75^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Conditions	Limits			Unit
			Min	Typ	Max	
V_{IH}	High-level input voltage		2			V
V_{IL}	Low-level input voltage				0.95	V
V_{IC}	Input clamp voltage	$V_{CC}=4.75\text{V}$, $I_{IC}=-5\text{mA}$			-1	V
V_{OH}	High-level output voltage, DO output	$V_{CC}=4.75\text{V}$ $V_{IH}=2\text{V}$ $V_{IL}=0.95\text{V}$	$I_{OH}=-1\text{mA}$ $I_{OH}=-10\text{mA}$ $I_{OL}=15\text{mA}$ $I_{OL}=25\text{mA}$ $I_{OL}=55\text{mA}$ $I_{OL}=50\text{mA}$	3.65		V
V_{OH}	High-level output voltage, DB output			2.4		V
V_{OL1}	Low-level output voltage, DO output				0.45	V
V_{OL1}	Low-level output voltage, DB output				0.45	V
V_{OL2}	Low-level output voltage, DB output	M5L8216P			0.6	V
		M5L8226P			0.6	V
I_{OZH}	Off-state output current, DO output	$V_{CC}=5.25\text{V}$	$V_O=5.25\text{V}$ $V_O=0.45\text{V}$		20	μA
I_{OZH}	Off-state output current, DB output				100	μA
I_{OZL}	Off-state output current, DO output				-20	μA
I_{OZL}	Off-state output current, DB output				-100	μA
I_{IH}	High-level input current, DIEN, CS inputs	$V_{CC}=5.25\text{V}$, $V_{IH}=4.5\text{V}$			20	μA
I_{IH}	High-level input current, DI, DB inputs	$V_{CC}=5.25\text{V}$, $V_{IH}=4.5\text{V}$			10	μA
I_{IL}	Low-level input current, DIEN, CS inputs	$V_{CC}=5.25\text{V}$, $V_{IH}=4.5\text{V}$			-500	μA
I_{IL}	Low-level input current, DI, DB input	$V_{CC}=5.25\text{V}$, $V_{IH}=4.5\text{V}$			-250	μA
I_{OS}	Short-circuit output DO output (Note 2)	$V_{CC}=5.25\text{V}$, $V_O=0\text{V}$	-15		-65	mA
I_{OS}	Short-circuit output, DB output (Note 2)	$V_{CC}=5.25\text{V}$, $V_O=0\text{V}$	-30		-120	mA
I_{CC}	Supply current	M5L8216P			100	mA
		M5L8226P			100	mA
I_{CCZ}	Supply current z	M5L8216P			120	mA
		M5L8226P			100	mA

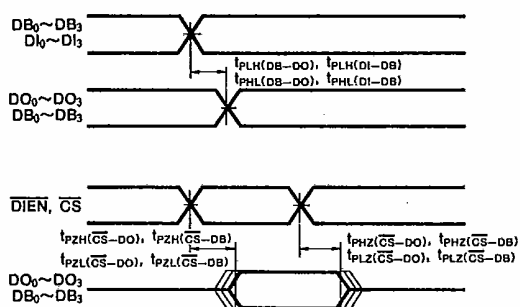
Note 1 : Current flowing into an IC is positive, out is negative.

2 : All measurements should be done quickly, and not more than one output should be shorted at a time.

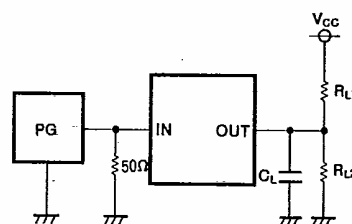
SWITCHING CHARACTERISTICS ($V_{CC}=5V \pm 5\%$, $T_a=25^\circ C$, unless otherwise noted)

Symbol	Parameter	Test conditions (Note 3)	Limits			Unit
			Min	Typ	Max	
$t_{PHL}(DB-DO)$ $t_{PLH}(DB-DO)$	High-to-low and low-to-high output propagation time, from input DB to output DO	$C_L=30pF$, $R_{L1}=300\Omega$, $R_{L2}=600\Omega$			25	ns
$t_{PHL}(DI-DB)$ $t_{PLH}(DI-DB)$	High-to-low and low-to-high output propagation time, from input DI to output DB	$C_L=300pF$, $R_{L1}=90\Omega$, $R_{L2}=180\Omega$			30	ns
$t_{PHZ}(\overline{CS}-DO)$ $t_{PLZ}(\overline{CS}-DO)$	High-to-Z and low-to-Z output propagation time, from inputs $\overline{DIEN}$, $\overline{CS}$ to output DO	$C_L=5pF$, $R_{L1}=10k\Omega$, $R_{L2}=1k\Omega$ $C_L=5pF$, $R_{L1}=300\Omega$, $R_{L2}=600\Omega$			35	ns
$t_{PZH}(\overline{CS}-DO)$ $t_{PLZ}(\overline{CS}-DO)$	Output enable time, from inputs $\overline{DIEN}$, $\overline{CS}$ to output DO	$C_L=30pF$, $R_{L1}=10k\Omega$, $R_{L2}=1k\Omega$ $C_L=30pF$, $R_{L1}=300\Omega$, $R_{L2}=600\Omega$			65	ns
$t_{PZH}(\overline{CS}-DB)$ $t_{PLZ}(\overline{CS}-DB)$	Output enable time, from inputs $\overline{DIEN}$, $\overline{CS}$ to output DB	$C_L=30pF$, $R_{L1}=10k\Omega$, $R_{L2}=1k\Omega$ $C_L=30pF$, $R_{L1}=90\Omega$, $R_{L2}=180\Omega$			65	ns
$t_{PZH}(\overline{CS}-DO)$ $t_{PLZ}(\overline{CS}-DO)$	Output disable time, from inputs $\overline{DIEN}$, $\overline{CS}$ to output DO	$C_L=5pF$, $R_{L1}=10k\Omega$, $R_{L2}=1k\Omega$ $C_L=5pF$, $R_{L1}=90\Omega$, $R_{L2}=180\Omega$			35	ns
$t_{PZH}(\overline{CS}-DB)$ $t_{PLZ}(\overline{CS}-DB)$	Output disable time, from inputs $\overline{DIEN}$, $\overline{CS}$ to output DB	$C_L=300pF$, $R_{L1}=10k\Omega$, $R_{L2}=1k\Omega$ $C_L=300pF$, $R_{L1}=90\Omega$, $R_{L2}=180\Omega$			65	ns

TIMING DIAGRAM (Reference level=1.5V)



Note 3 : Test circuit



APPLICATION EXAMPLES

Fig. 1 shows a pair of M5L8216Ps or M5L8226Ps which are directly connected with the 8080A CPU data bus, and their control signal. Fig. 2 shows an example circuit in which the M5L8216P or M5L8226P is used as an interface for memory and I/O to a bidirectional bus.

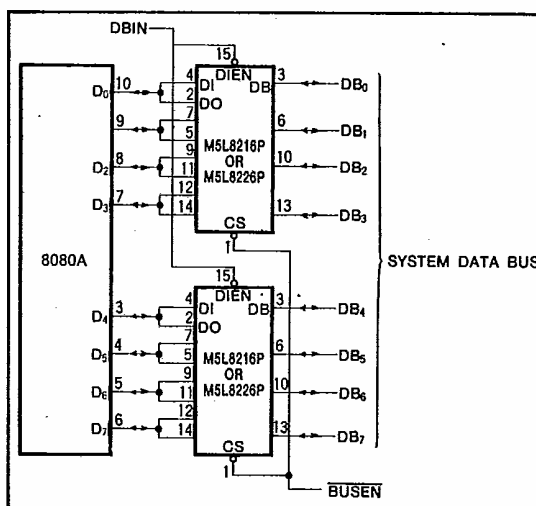


Fig. 1 Data bus buffer

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4-BIT PARALLEL BIDIRECTIONAL BUS DRIVERS

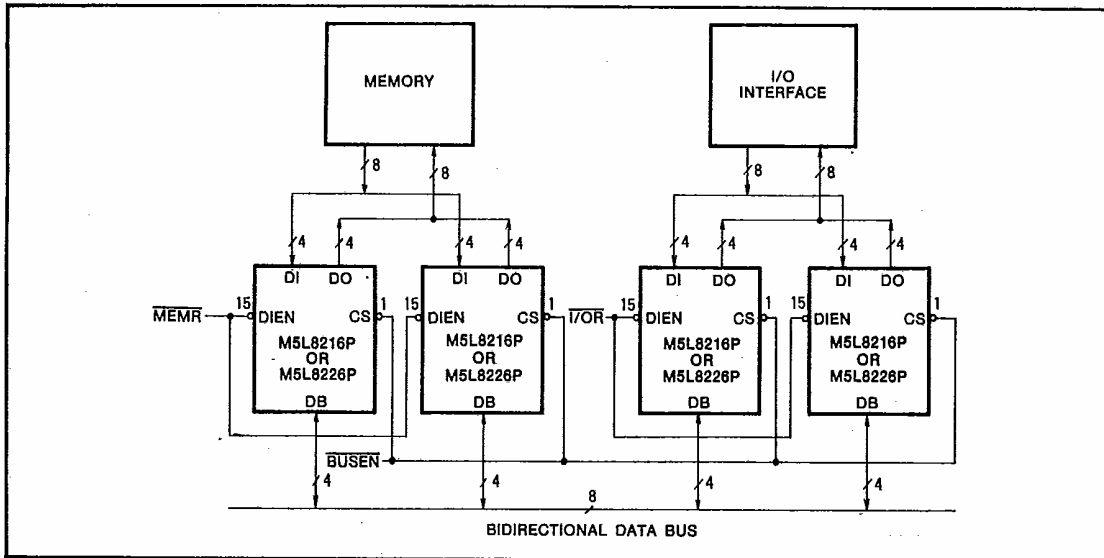


Fig. 2 Memory and I/O Interface to bidirectional data bus

PRECAUTIONS FOR USE

When the M5L8216P data input or two-way data bus is set to high to disable-output from the two-way bus or data output, care is required as a low glitch of approximate width 10ns will be generated.